Substitute	Substitute for form 1449B/PTO			Complete if Known		
INFORMATION DISCLOSURE			OL OCUPE	Application Number	10/781,334	
				Filing Date	February 17, 2004	
STAT	EMENT E	BY A	PPLICANT	First Named Inventor	Cameron McClintock	
				Art Unit	2819	
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Sheet	4	of	4	Attorney Docket Number	015114-052530US	

		NON PATENT LITERATURE DOCUMENTS	
Examiner Initials *	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T 2
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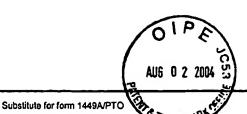
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